



Istituto Nazionale di Fisica Nucleare



TRILLION

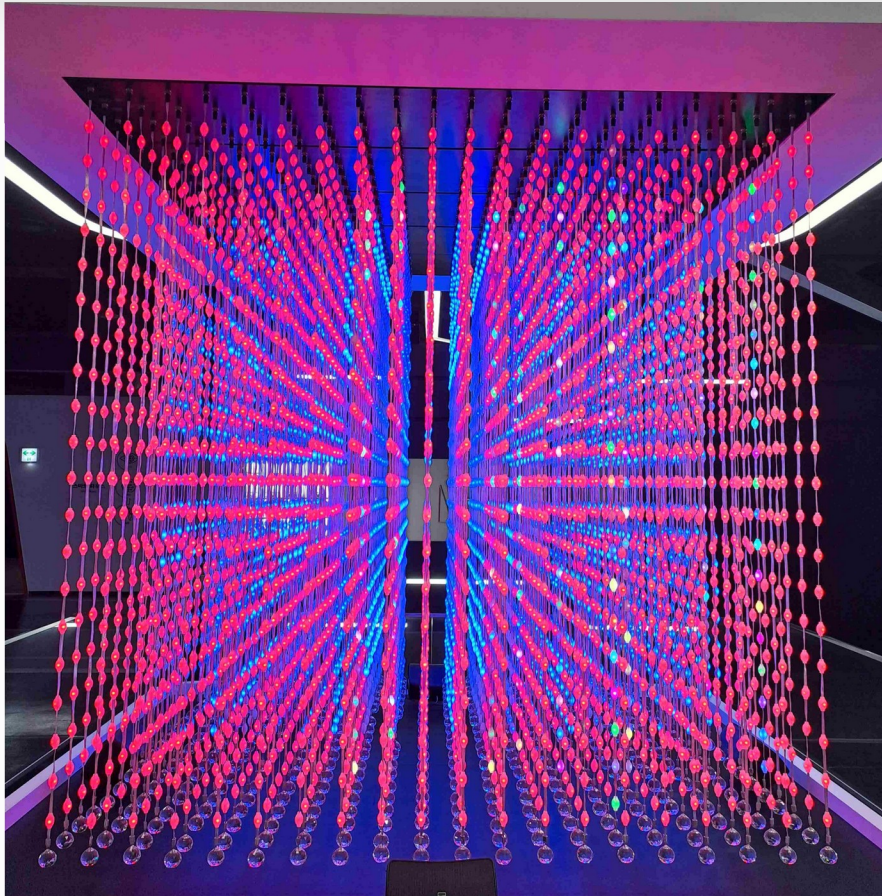
Geant4 ab-initio models on channeling, channeling radiation and coherent pair production in oriented crystals

Marie Curie Global Fellowships, Project TRILLION GA n. 101032975

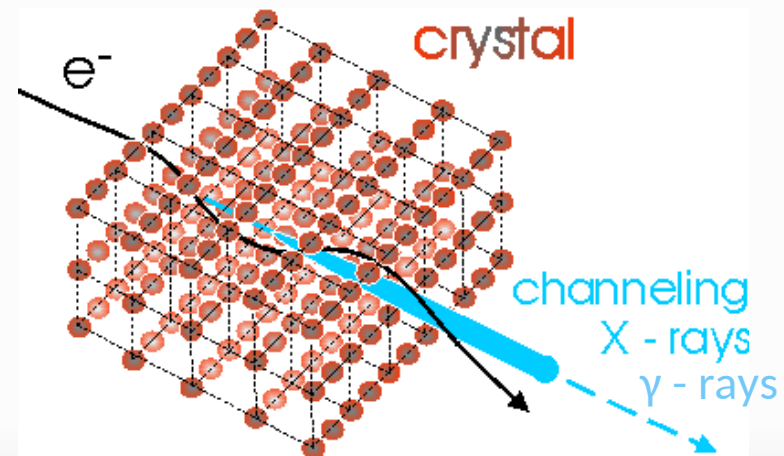
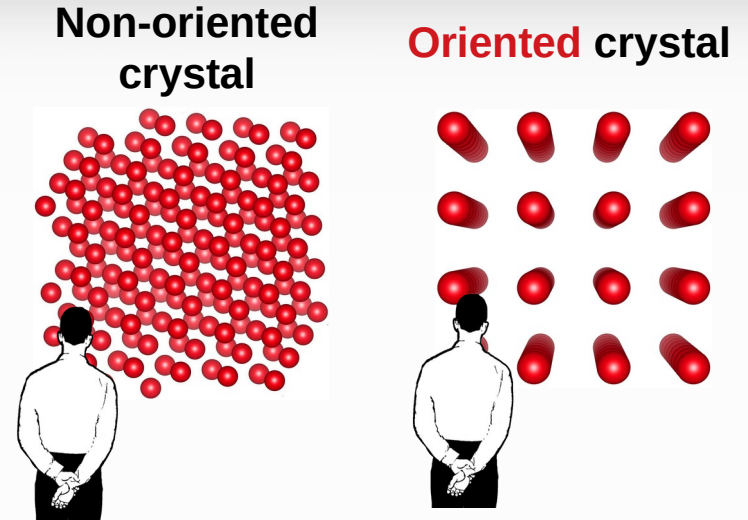
**A. Sytov, G. Paternò,
L. Bandiera, K. Cho, G.A.P. Cirrone, S. Guatelli, V. Haurylavets, S. Hwang,
V. Ivanchenko, R. Negrello, L. Pandola, A. Rosenfeld, V. Tikhomirov**

29th Geant4 Collaboration Meeting, 10/10/2024

How an oriented crystal looks like



from National Science
Museum, Daejeon, Korea



Marie Skłodowska-Curie Action Global Individual Fellowships by A. Sytov in 2021-2025, Project TRILLION GA n. 101032975

Main goal: The **implementation** of both physics of **electromagnetic processes in oriented crystals** and the design of specific applications of crystalline effects into **Geant4** simulation toolkit as Extended Examples to bring them to a large scientific and industrial community and under a free Geant4 license.

Group:

- **A. Sytov** – project coordinator
- **L. Bandiera** – INFN supervisor
- **K. Cho** – KISTI supervisor
- **G. Kube** – DESY supervisor
- **I. Chaikovska** – IJCLab Orsay supervisor

Location:

- 2 years at **KISTI** (partner organization)
- 1 year at **INFN Section of Ferrara** (host organization)
- 1 month of secondment at **DESY** (partner organization)
- 1 month of secondment at **IJCLab Orsay** (partner organization)



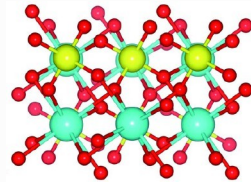
Applications*

Crystal-based collimation or beam extraction from an accelerator

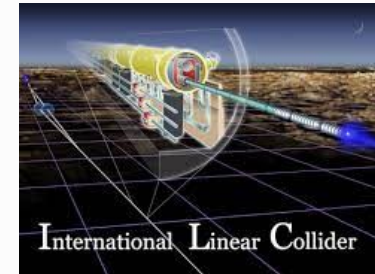
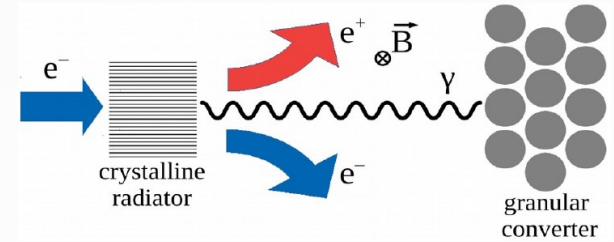


Gamma-ray Space Telescope

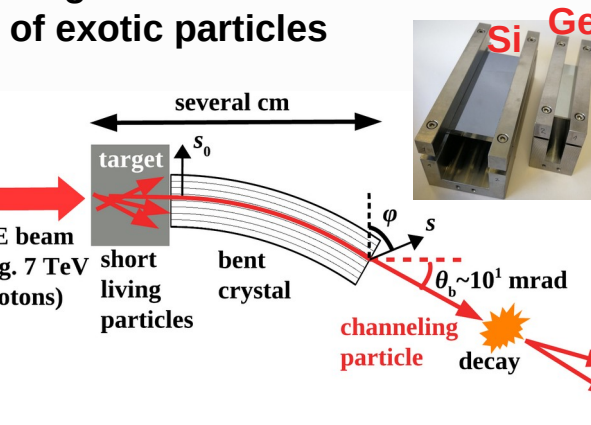
Ultrashort crystalline calorimeter



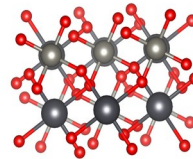
Positron source for future e⁺/e⁻ and muon colliders



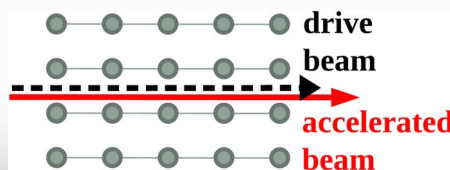
Measurement of dipole magnetic and electric moments of exotic particles



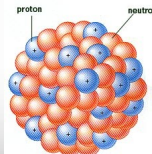
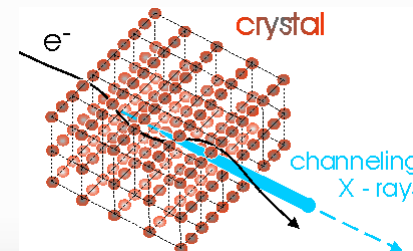
Oriented crystals



Plasma acceleration

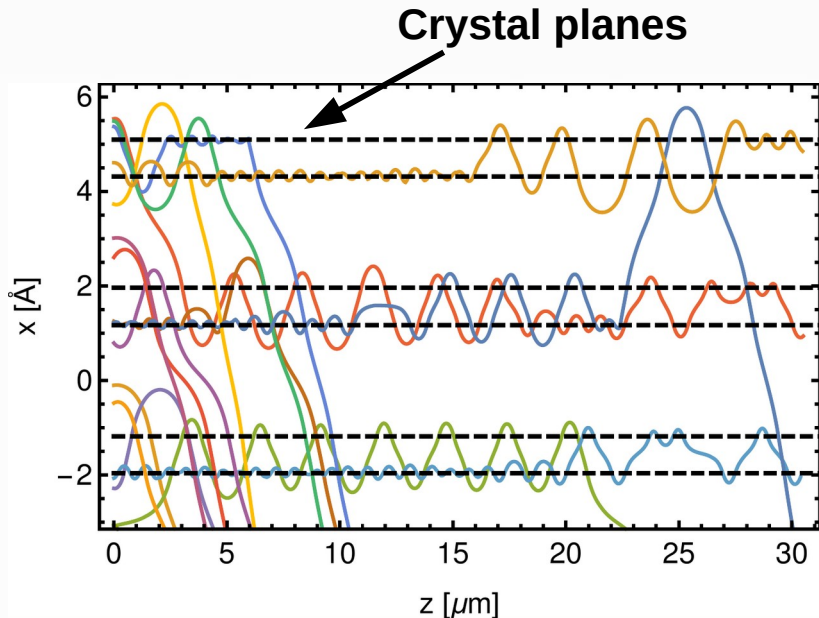


X and γ-ray source for nuclear and medical physics



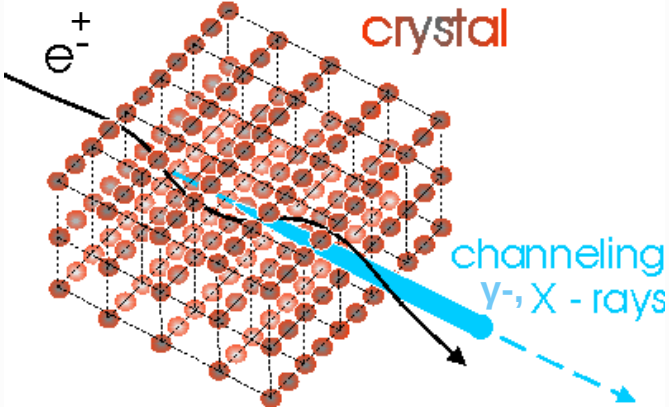
G4ChannelingFastSimModel and G4BaierKatkov

Main conception – simulation of classical trajectories of charged particles in a crystal in averaged atomic potential of planes or axes. Multiple and single **scattering simulation** at every step



**New 2024:
ionization losses
in channeling**

channeling*



Baier-Katkov formula:
integration is made over the classical trajectory

$$\frac{dE}{d^3k} = \omega \frac{dN}{d^3k} \frac{\alpha}{4\pi^2} \iint dt_1 dt_2 \frac{[(E^2 + E'^2)(v_1 v_2 - 1) + \omega^2 / \gamma^2]}{2E'^2} e^{-ik'(x_1 - x_2)}$$

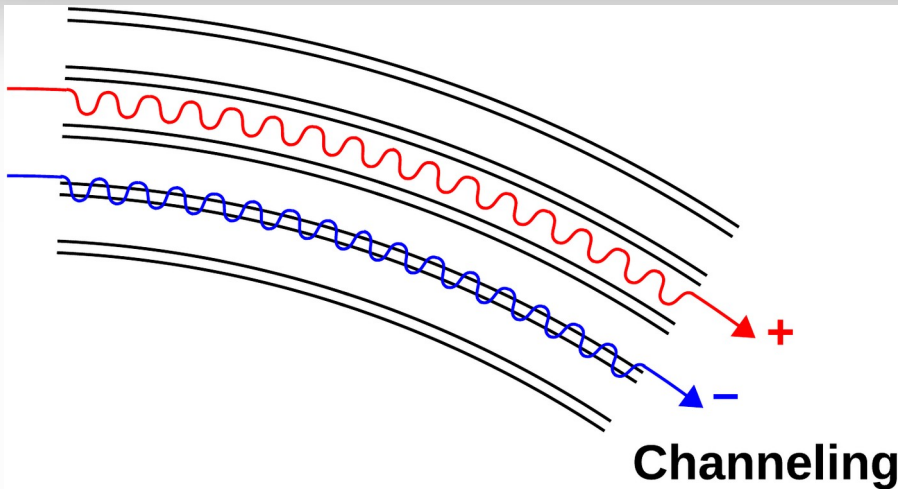
A.I. Sytov, V.V. Tikhomirov. NIM B 355 (2015) 383–386.

L. Bandiera, et al., Nucl. Instrum. Methods Phys. Res., Sect. B 355, 44 (2015)

A. I. Sytov, V. V. Tikhomirov, and L. Bandiera. PRAB 22, 064601 (2019)

*A. Sytov et al. Journal of the Korean Physical Society 83, 132–139 (2023)

Channeling



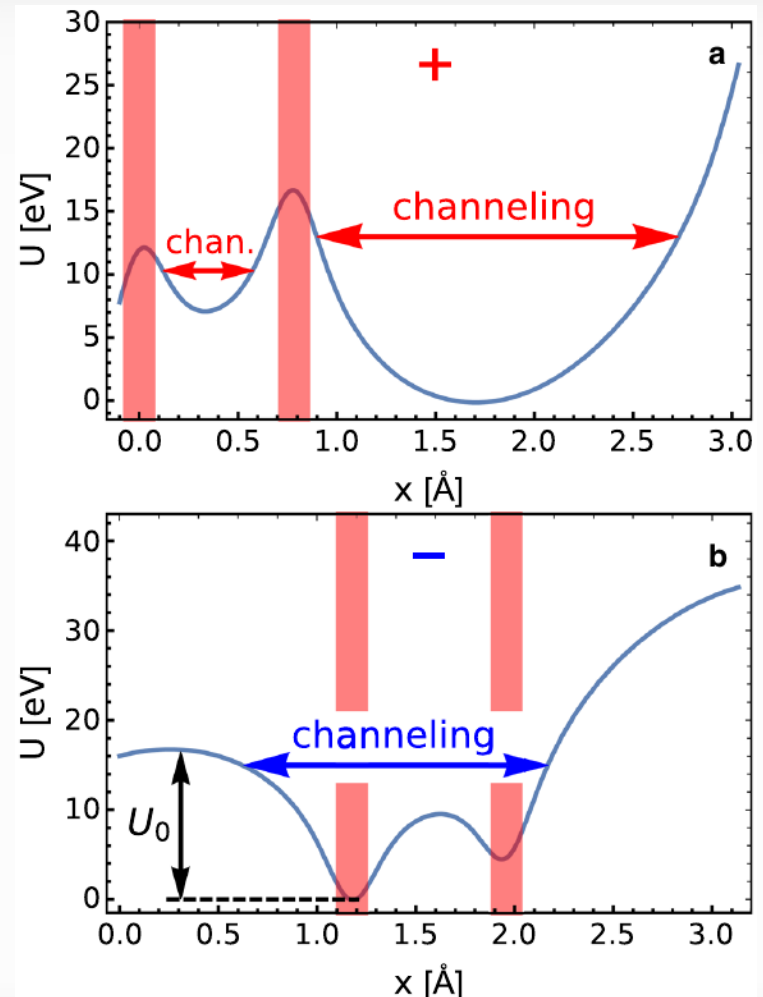
Channeling*:

Charge particle penetration through a monocrystal along its atomic planes/axes

trajectory equation:

$$\frac{d^2x}{dz^2} + \frac{U'_{pl\ x}}{pv} + \frac{1}{R} = 0$$

Interplanar potential



*J. Lindhard, Kgl. Dan. Vid. Selsk. Mat.-Fys. Medd. 34 No 4, 2821–2836 (1965)

E.N. Tsyganov, Fermilab TM-682 (1976)

**A. Sytov et al., Eur. Phys. J. C (2022) 82:197

The model of Coulomb scattering

Coulomb scattering cross-section on atom following from screened Coulomb potential:

$$\frac{d\sigma_{cr}}{d\Omega} = \frac{d\sigma_{coh}}{d\Omega} + \frac{d\sigma_{inc}}{d\Omega}$$

Motion in averaged potential

$$\frac{d\sigma_{inc}}{d\Omega} = N(1 - D) \frac{d\sigma_{at}}{d\Omega}$$

Debye-Waller factor

Coulomb scattering process is divided into multiple and single scattering:

● **Multiple scattering $\vartheta \leq \vartheta_2$:**

$$\langle \vartheta_{Cms}^2 \rangle = \langle n_N \rangle \Delta z \int_0^{\vartheta_2} \int_0^{2\pi} \frac{d\sigma_C}{d\Omega} (1 - \exp(-p^2 \vartheta^2 u_1^2)) d\varphi \vartheta^3 d\vartheta$$

Debye-Waller factor

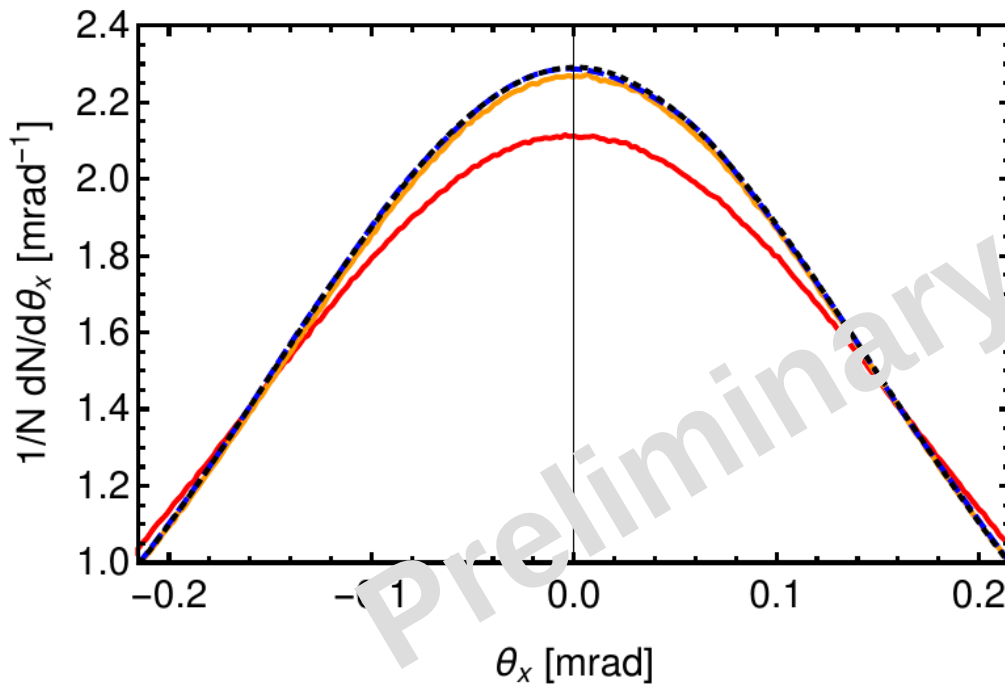
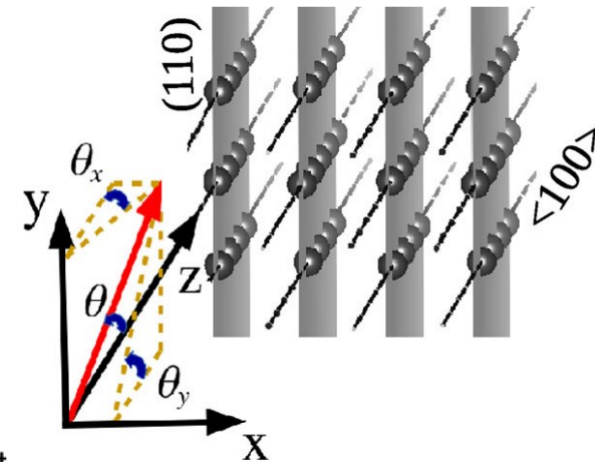
● **Single scattering $\vartheta > \vartheta_2$ by (1) and taking into account the Debye-Waller factor.**

● **Single scattering on electrons, Rutherford cross-section:**

$$\frac{d\sigma_{Ce}}{d\Omega} = 4 \frac{z^2 e^4}{p^2 v^2} \frac{1}{\vartheta^4}$$

2D Geant4 channeling model validation: coherent scattering suppression effect*

Multiple scattering in crystal and multiple scattering in amorphous material are different!



- Experiment amorphous Si
- Experiment Si $\langle 100 \rangle$ (0.172°, 2°)
- - - Geant4 Si $\langle 100 \rangle$ (0.172°, 2°)
- - - CRYSTALRAD Si $\langle 100 \rangle$ (0.172°, 2°)

To be submitted for publication soon

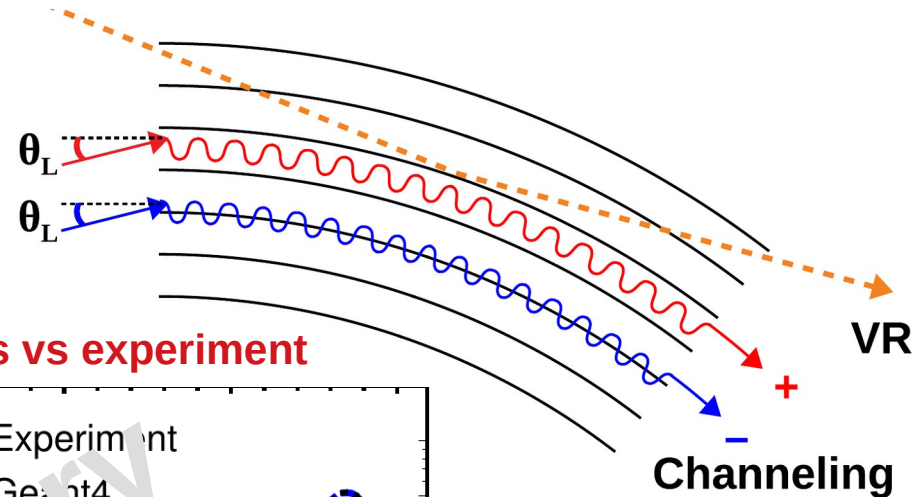
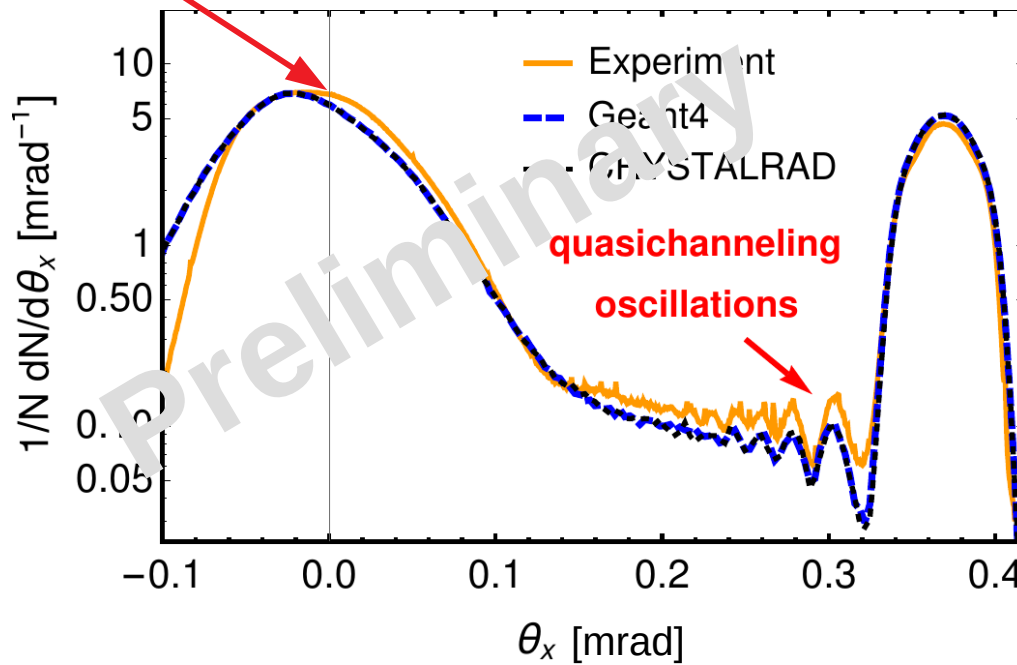
More Geant4 channeling model validation: quasichanneling oscillations* at SLAC FACET Facility

20.35 GeV
positrons

60 μm thick
bent crystal

volume reflection (VR)

Geant simulations vs experiment



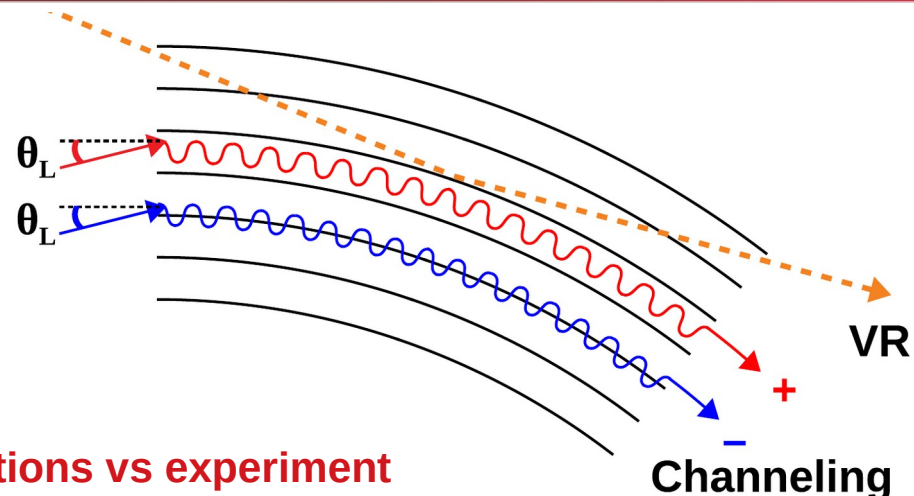
To be submitted for publication soon

Recent experiment Channeling of 530 MeV positrons in a bent crystal

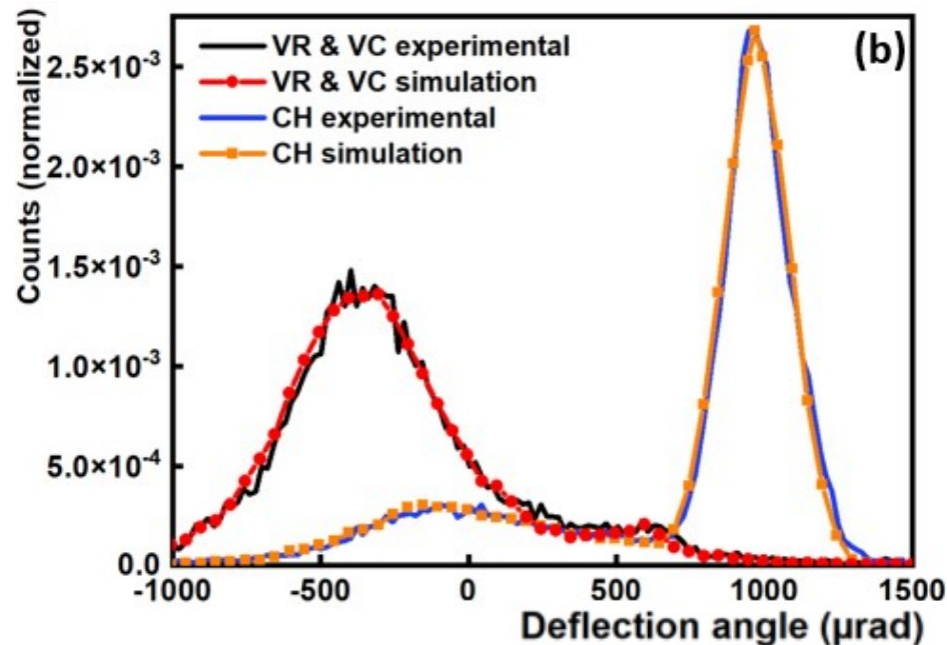
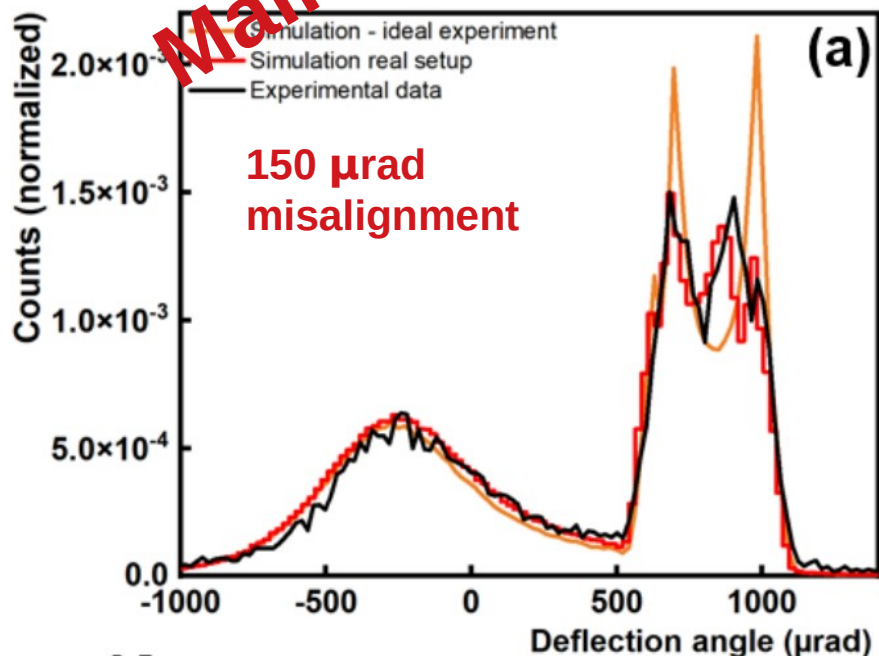
530 MeV positrons

30 μm thick bent crystal

**New experiment
Mainz Mikrotrotron 2024**



Geant4 simulations vs experiment



Main concept of full ab-initio G4BaierKatkov

$$\frac{dE}{d^3k} = \omega \frac{dN}{d^3k} \frac{\alpha}{4\pi^2} \iint dt_1 dt_2 \frac{[(E^2 + E'^2)(v_1 v_2 - 1) + \omega^2 / \gamma^2]}{2E'^2} e^{-ik'(x_1 - x_2)}$$

Monte Carlo integration by photon
3 components of momentum

Monte Carlo integration by
photon **energy** and **angles**

\vec{k}

$\omega, \theta_x, \theta_y$

Radiation probability
calculated per photon

$\vec{k}_i \Rightarrow P_i$

If radiation happens, **select a photon** from using **P_i** as their **weight** and generate it

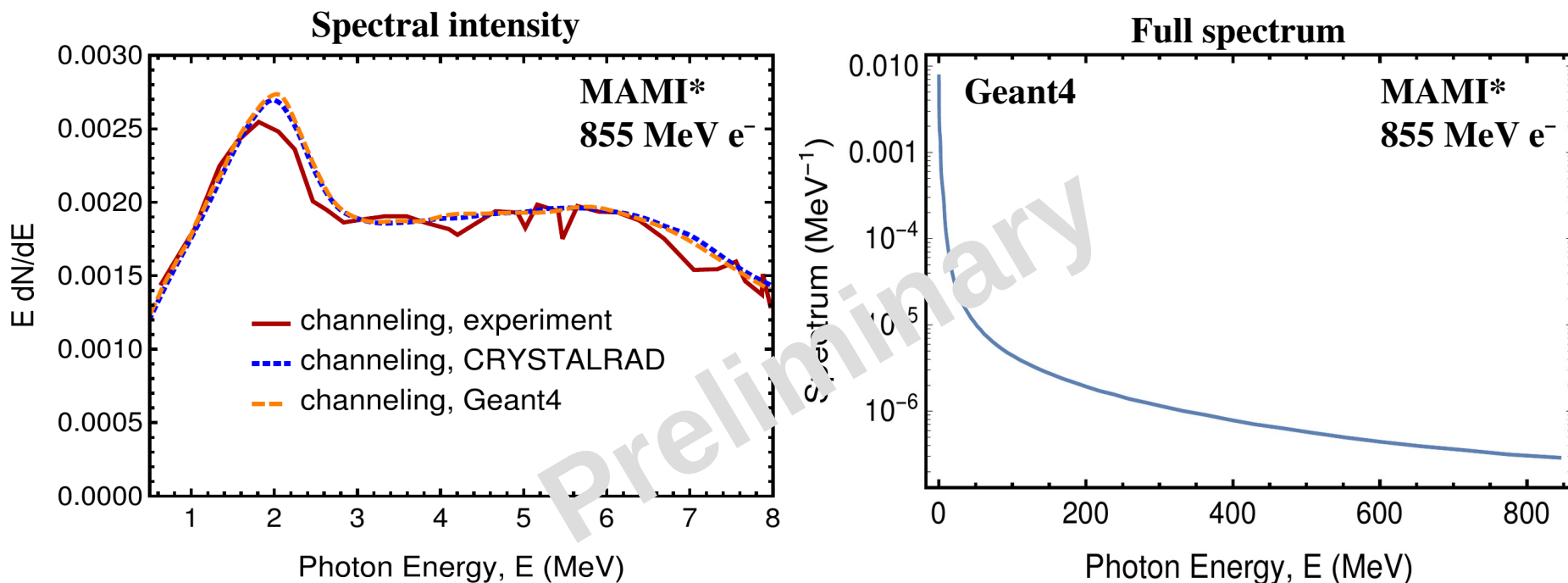
Photon **energy** and **angular distribution** naturally comes from **Baier-Katkov**

First Geant4 Baier-Katkov radiation model: radiation by 855 MeV electrons at Mainz Mikrotron MAMI*

G4BaierKatkov:

- **Physics list independent**
- Can be used **outside channeling model** within other FastSim model
- Provides **radiation spectrum** for single-photon radiation mode
- Provides generation of **secondary photons**

Geant simulations vs experiment and CRYSTALRAD simulations



To be submitted for publication soon

How to implement an external code into Geant4?

Geant4 FastSim interface, solution to most of challenges

FastSim model:

- Physics list **independent**
- Declared in the **DetectorConstruction** (just **few lines of code**)
- Is activated **only** in a **certain G4Region** at a **certain condition** and only for **certain particles**
- **Stops Geant processes** at the step of FastSim model and then resumes them

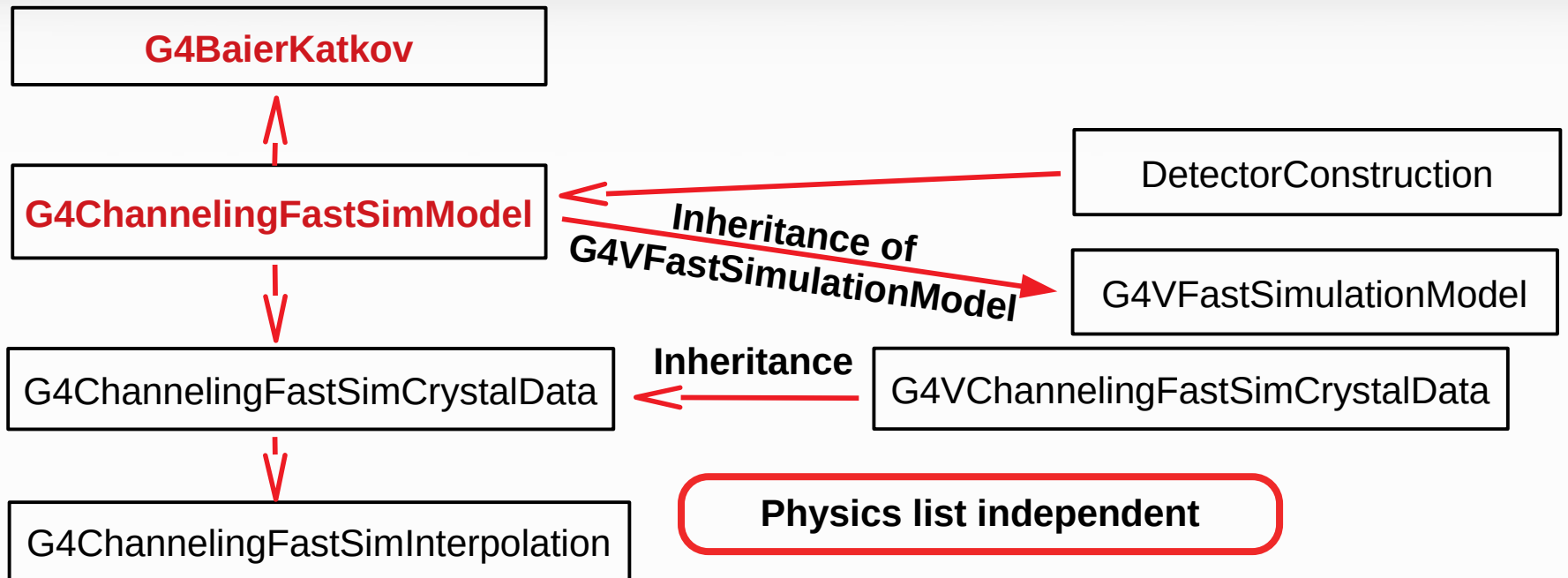
```
71  G4bool TestModel::IsApplicable(const G4ParticleDefinition& particleType)
72  {
73      return
74      &particleType == G4Proton::ProtonDefinition() ||
75      &particleType == G4AntiProton::AntiProtonDefinition() ||
76      &particleType == G4Electron::ElectronDefinition() ||
77      &particleType == G4Positron::PositronDefinition(); // ||
78      //&particleType == G4Gamma::GammaDefinition();
79  }
80
81  //.....ooo0000ooo.....ooo0000ooo.....ooo0000ooo.....ooo0000ooo.....
82
83  G4bool TestModel::ModelTrigger(const G4FastTrack& fastTrack)
84  {
102  }
103
104  //.....ooo0000ooo.....ooo0000ooo.....ooo0000ooo.....ooo0000ooo.....
105
106  void TestModel::DoIt(const G4FastTrack& fastTrack,
107                      G4FastStep& fastStep)
108  {
```

Insert particles for which the model is applicable

Insert the condition to enter the model

Insert what the model does

Structure of classes



Additional classes:

- **G4VChannelingFastSimCrystalData**: multiple and single Coulomb scattering, ionization losses
- **G4ChannelingFastSimCrystalData**: read crystal lattice data files from **G4CHANNELINGDATA**, logical volume to crystal plane/axis geometry transformation
- **G4ChannelingFastSimInterpolation**: crystal lattice data and 3D-spline interpolation functions

Current status

In Geant4 since geant4-11.2.0 !

geant4-v11.2.0/source/parameterisations/channeling/

Please use it!

<https://geant4.web.cern.ch/download>

**Don't hesitate to contact me in the case of
any problems/issues/suggestions**

sytov@fe.infn.it

Geant4 Physics Reference Manual:

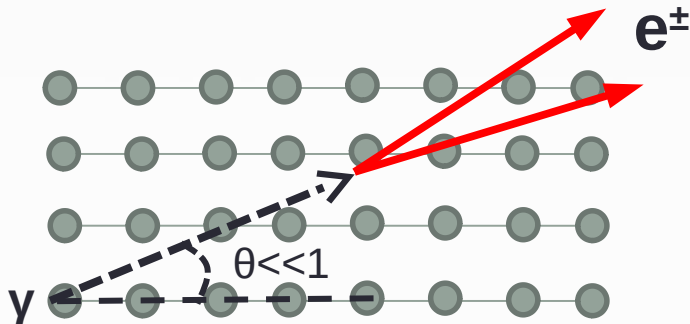
https://geant4-userdoc.web.cern.ch/UsersGuides/PhysicsReferenceManual/html/solidstate/channeling/channeling_fastsim.html

Please cite our papers if you use our model:

1. A. Sytov et al. Journal of the Korean Physical Society 83, 132–139 (2023)
2. A. I. Sytov, V. V. Tikhomirov, and L. Bandiera. PRAB 22, 064601 (2019)

New 2024: Coherent pair production Geant4 process

Coherent pair production***



Key idea:

- Randomly **generate e± pairs**
- **Track e±** in the crystal
- Use **Baier-Katkov** formula to calculate the **probability of pair production**
- Randomly **select a pair according to this probability** and generate secondaries

G4CoherentPairProduction

G4CoherentPairProductionPhysics



G4ChannelingFastSimCrystalData

G4VChannelingFastSimCrystalData

Inheritance

G4ChannelingFastSimInterpolation

Can work in parallel with standard physics list

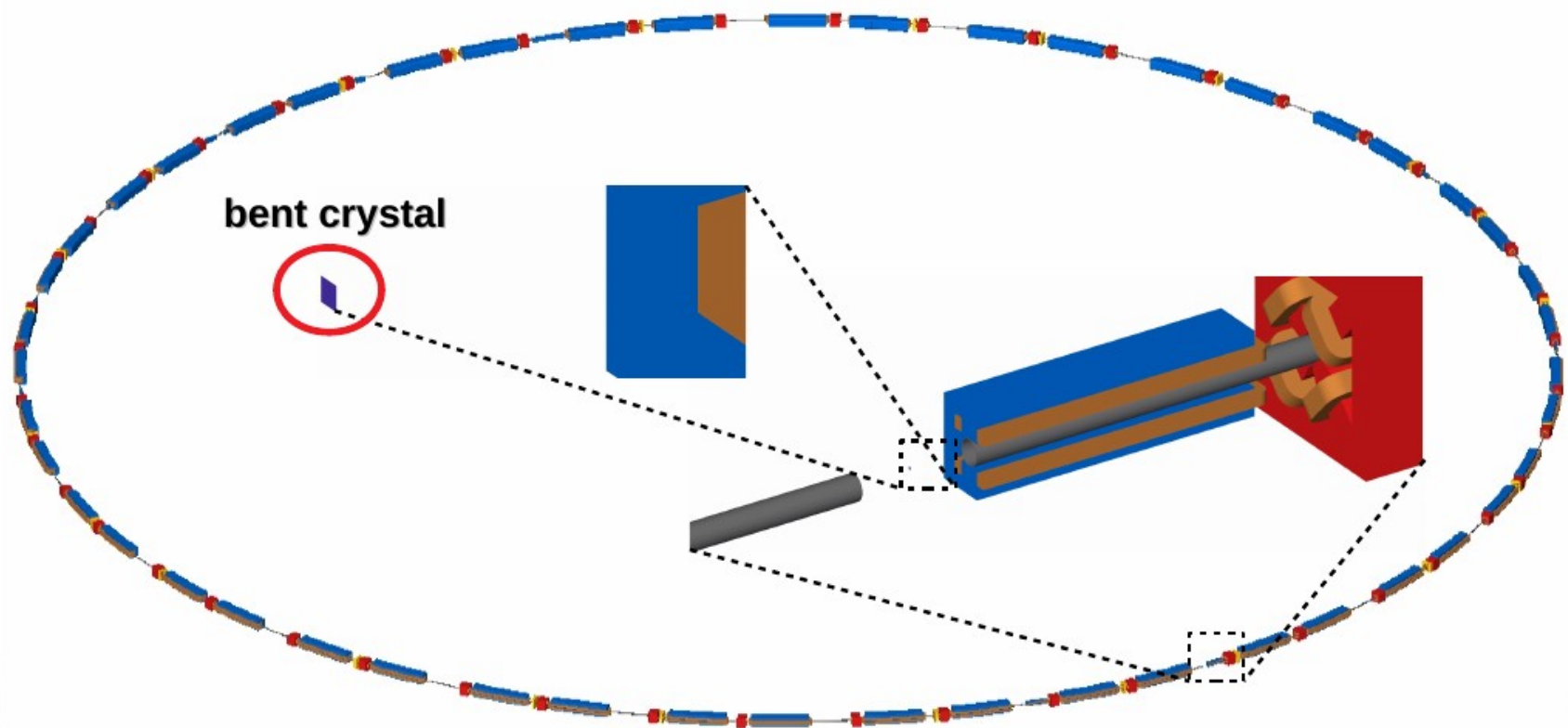
*** H. Überall, Phys. Rev. 103, 1055 (1956)

My mission to DESY: full simulations with the BDSim simulation code



Purpose of BDSIM:

Beam Delivery Simulation (BDSIM) is a C++ program that utilises the **Geant4 toolkit** to simulate both the **transport of particles in an accelerator** and their **interaction with the accelerator material**. BDSIM is capable of **simulating a wide variety of accelerator components and magnets** with Geant4 geometry dynamically built based on a text input file. **Thick lens accelerator tracking routines** are provided for fast accurate tracking in a vacuum.



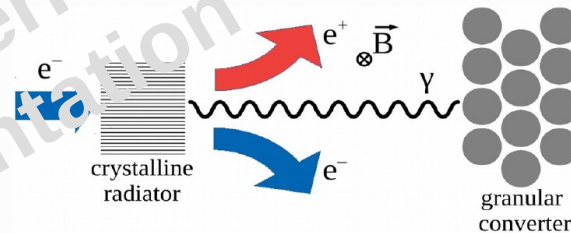
To include in Geant4 in 2024

Examples:

● **ch1** a very **easy example** to demonstrate basic commands to include the channeling model in DetectorConstruction (no input/simple output)

● **ch2** a **complex example** including both channeling and radiation model, crystalline undulator, input with macro commands, root output and full spectrum of options

● **Crystal-based hybrid positron source for FCC-ee**



Merged

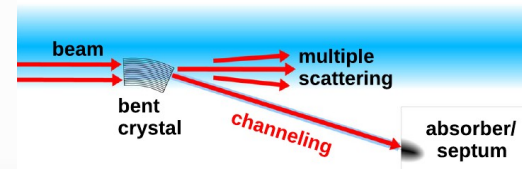
Merged

Prepared

● **Pair production model** and dedicated example of electromagnetic shower in a scintillator crystal

Model prepared;
example in 2025

● **Crystalline deflector to extract a charged particle beam from an accelerator** (electron synchrotron, hadron collider) using **BDSim** code



Works

Acknowledgments

Marie Sklodowska-Curie Action Global Individual Fellowships TRILLION (G.A. 101032975) is in synergy with the following projects I would like to acknowledge:

- **GEANT4INFN** project (INFN Geant4 group);
- **INFN OREO, PRIN E+BOOST, INFN GALORE, RD-MUCOL, RD-FCC,**
- **H2020-MSCA-RISE N-LIGHT** (G.A. 872196) and **EIC-PATHFINDER-OPEN TECHNO-CLS** (G.A. 101046458) projects.
- We acknowledge the **CINECA** award under the **ISCRA** initiative, for the availability of high-performance computing resources and support.
- This work is also supported by the Korean National Supercomputing Center with supercomputing resources including technical support (**KSC-2022-CHA-0003**).

I also thank the **Geant4 collaboration** members, in particular:

Prof. Vladimir Ivanchenko (CERN), Prof. Pablo Cirrone and Dr. Luciano Pandola (INFN LNS), Prof. Kihyeon Cho, Prof. Soonwook Hwang and Dr. Kyungho Kim (KISTI), Prof. Susanna Guatelli and Prof. Anatoly Rosenfeld (University of Wollongong), Dr. Gianfranco Paternò (INFN Ferrara) as well as Prof. Makoto Asai (Jlab) and Prof. Marc Verderi (IN2P3/LLR) for fruitful collaboration and discussions!

GANGNAM STYLE



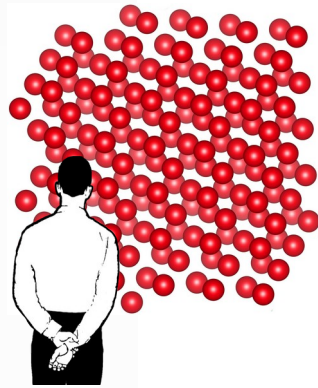
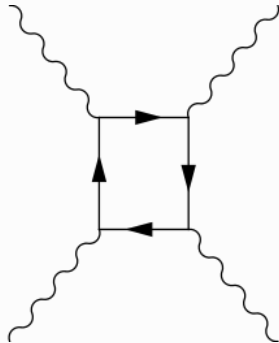
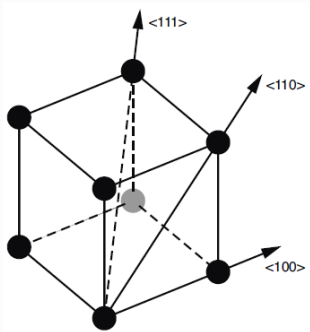
감사합니다!

Electromagnetic shower acceleration

Axial field
 10^{11} V/cm



Approaching the **Schwinger limit** starting from few GeV for e^+/e^-



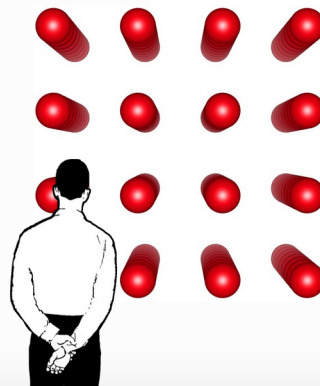
Particle

Amorphous or randomly oriented crystal

Oriented crystal

Particle

The **radiation intensity** and the **pair production cross-section** drastically increase in **oriented crystals!**



Shower development in the field of axes is **accelerated**. The radiation length is considerably reduced.

Why the implementation of channeling and Baier-Katkov models into Geant4 is so challenging?

Challenges of trajectory simulation

- **Complicated geometry** of crystal planes/axes especially in a bent crystal;
- **Complicated spacial structure** of cristalline **electric fields** and **atomic density** depending on the material and alignment;
- Different types of **scattering dependent** on the charge particle **positions** vs crystal planes/axes;
- **Incompatibility** of channeling with **Geant4 standard physics lists**: especially with **multiple coulomb scattering** and **bremsstrahlung** process: impossible to modify **continuous-discrete Geant4** processes during execution.

Challenges of Baier-Katkov

- Need for **recording trajectory** in order to simulate the spectrum;
- Multidimensional integral => **low simulation speed**;
- Hard gamma radiation => need to **return the particle back to the radiation point**, which is **not allowed in Geant4** in a simple way.

Old channeling model in Geant4

Currently implemented*

Channeling physics:

- Only trajectories (**no radiation**)
- Only for hadrons
- Changing cross-sections using **Geant4 Biasing**

To do:

- To resolve the **problems** with modification of **continuous discrete processes**
- To add channeling of **e+/e-**
- To add channeling **radiation**
- To add coherent **pair production**

Problem with modification of the **electromagnetic physics list**:

class G4ChannelingOptrChangeCrossSection

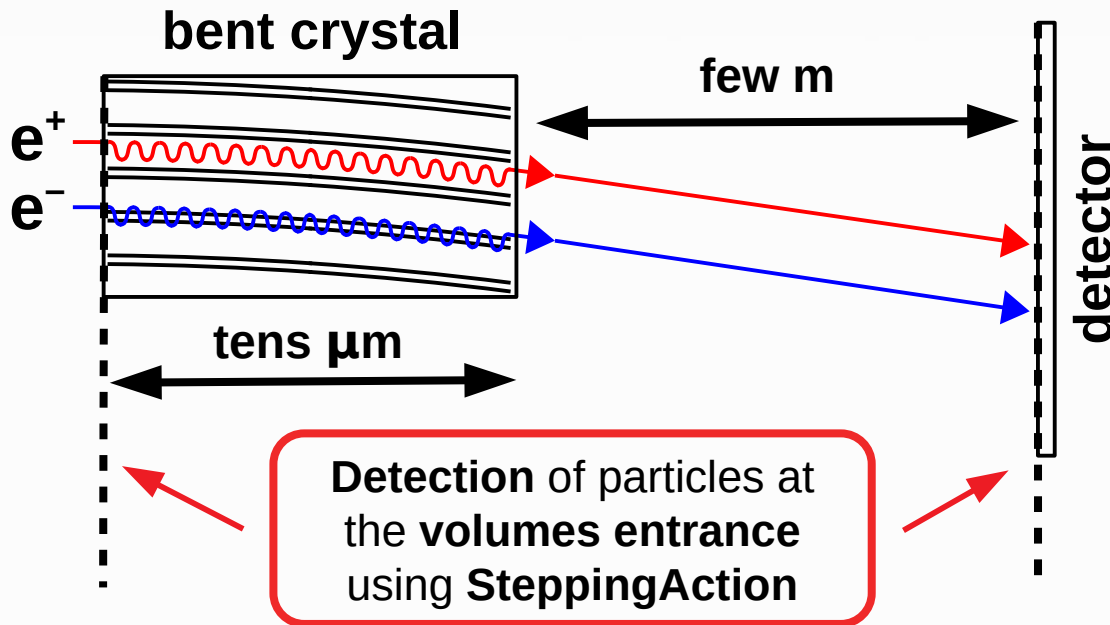
```
93
94
95
96
97
98
99
100
101
102
103
104
105
106
107
108
109
110
111
112
113
switch (type) {
  case fNotDefined:
    fProcessToDensity[processName] = fDensityRatioNone;
    break;
  case fTransportation:
    fProcessToDensity[processName] = fDensityRatioNone;
    break;
  case fElectromagnetic:
    if(subType == fCoulombScattering ||
       subtype == fMultipleScattering){
      fProcessToDensity[processName] = fCancelProcess;
    }
    if(subType == fIonisation ||
       subtype == fBremsstrahlung){
      fProcessToDensity[processName] = fCancelProcess;
    }
    if(subType == fPairProdByCharged ||
       subtype == fAnnihilation ||
       subtype == fAnnihilationToMuMu ||
       subtype == fAnnihilationToHadrons){
```

It is not possible to turn off/to modify **continuous discrete processes** (multiple scattering, ionization losses) in this way but only **discrete processes**

Crucial for e+/e- though not so important for high energy protons

First Geant4 channeling example for electrons/positrons

- **Inspired by our experiments* of 855 MeV electron beam deflection by an ultrashort bent crystal at Mainz Mikrotron MAMI**



Multithreading works!
Checked at the supercomputer
Galileo100@CINECA (Italy)
NURION@KISTI (Korea)

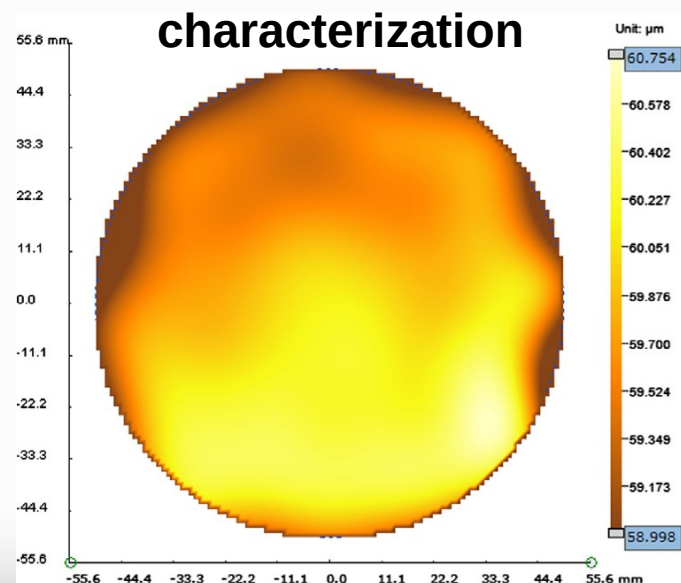
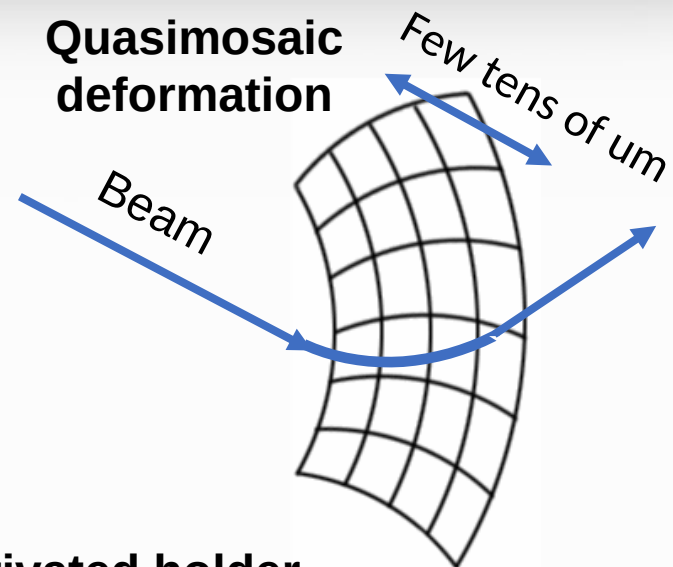
Output both in **root** (only primary particles)
and in **textfile** (all the particles) format



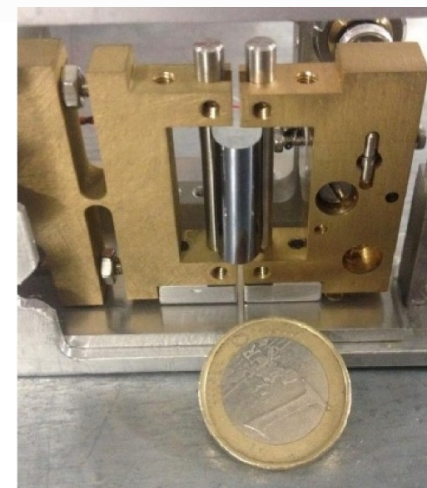
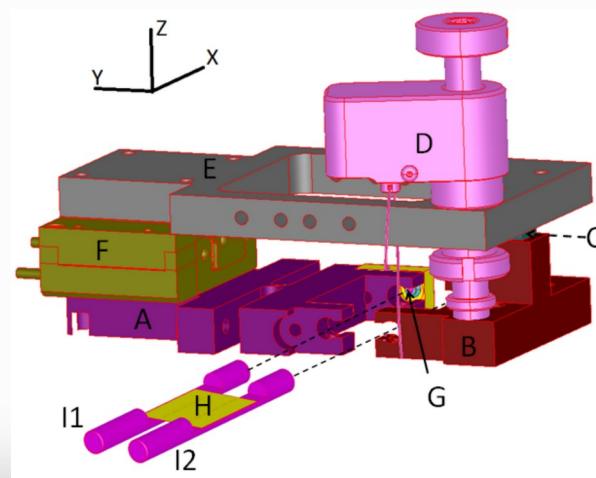
*A. Mazzolari et al. Phys. Rev. Lett. 112, 135503 (2014)

A. Sytov et al. Eur. Phys. J. C 77, 901 (2017)

Manufacturing and characterization of bent silicon crystals @INFN Ferrara



Piezo-activated holder



How to use the Geant4 channeling model in your example?

● Add to DetectorConstruction::Construct()

```
//crystal volume
G4Box* crystalSolid = new G4Box("Crystal",CrystalSizeX/2,CrystalSizeY/2,CrystalSizeZ/2.);
crystalLogic = new G4LogicalVolume(crystalSolid,crystalMaterial,"Crystal");
    new G4PVPlacement(xRot,posCrystal,crystalLogic,"Crystal",logicWorld,false,0);
//crystal region (necessary for the FastSim model)
fRegion = new G4Region("Crystal");
fRegion->AddRootLogicalVolume(crystalLogic);
```

Volume declaration
(completely standard)

G4Region declaration

● Add to DetectorConstruction::ConstructSDandField()

```
void DetectorConstruction::ConstructSDandField()
{
    // ----- fast simulation -----
    //extract the region of the crystal from the store
    G4RegionStore* regionStore = G4RegionStore::GetInstance();
    G4Region* RegionCh = regionStore->GetRegion("Crystal");

    //create the channeling model for this region
    G4ChannelingFastSimModel* ChannelingModel =
        new G4ChannelingFastSimModel("ChannelingModel", RegionCh);
    //activate the channeling model
    ChannelingModel->Input(crystalMaterial, Lattice);
    //setting bending angle of the crystal planes (default is 0)
    ChannelingModel->GetCrystalData()->
        SetBendingAngle(BendingAngle,crystalLogic);

    //activate radiation model
    if (ActivateRadiationModel) ChannelingModel->RadiationModelActivate();
}
```

Get crystal region

Channeling FastSim
model declaration

Model activation
and input

Optional

Radiation model
activation

Update of multiple scattering theory for the crystal case (in analogy to the Bremsstrahlung theory)*

- **Coulomb scattering cross-section** on an target consisting of N atoms in general case:

$$\frac{d\sigma}{d\Omega} = \left| \sum_{j=1}^N e^{i\mathbf{q}\cdot\mathbf{r}_j} \right|^2 \frac{d\sigma_{at}}{d\Omega} \quad (1)$$

- **Coulomb scattering cross-section** on an amorphous target consisting of N atoms:

$$\frac{d\sigma_{am}}{d\Omega} = N \frac{d\sigma_{at}}{d\Omega} \quad (2)$$

- For the **crystal case** the cross-section is divided onto the **coherent** and **incoherent** ones:

$$\frac{d\sigma_{cr}}{d\Omega} = \frac{d\sigma_{coh}}{d\Omega} + \frac{d\sigma_{inc}}{d\Omega} \quad (3)$$

where **coherent scattering cross-section**:

$$\frac{d\sigma_{coh}}{d\Omega} = \textcircled{D} \sum_{j=1}^N e^{i\mathbf{q}\cdot\mathbf{r}_{j0}} \left| \frac{d\sigma_{at}}{d\Omega} \right|^2$$

incoherent scattering cross-section:

$$\frac{d\sigma_{inc}}{d\Omega} = N(1 - \textcircled{D}) \frac{d\sigma_{at}}{d\Omega} = \frac{d\sigma_{am}}{d\Omega} - \frac{d\sigma_1}{d\Omega}$$

Debye-Waller
factor

Update of multiple scattering theory for the crystal case: Coherent scattering suppression effect*

- The **cross-section** for a **crystal** may be either **higher** or **lower** than for amorphous target:

$$\frac{d\sigma_{cr}}{d\Omega} = \frac{d\sigma_{coh}}{d\Omega} + \frac{d\sigma_{inc}}{d\Omega} \quad (1)$$

Depends on the
crystal alignment

- **At certain crystal alignment coherent scattering $\rightarrow 0$:**

$$d\sigma \xrightarrow{d\sigma_{coh}=0} d\sigma_{am} - d\sigma_1$$

we call this effect **Coherent scattering suppression (CSS)**

- The **minimal scattering angle** in the **G. Molière** theory** ϑ_{min}^{am} transforms for the **crystal** case into:

$$\ln \vartheta_{min}^{cr} = \ln \vartheta_{min}^{am} + \frac{0.5Z}{Z+1} \left[\left(1 + \frac{u_1^2}{R^2} \right) e^{\frac{u_1^2}{R^2}} E_1 \left(\frac{u_1^2}{R^2} \right) - 1 \right]$$

Molière angular
distribution

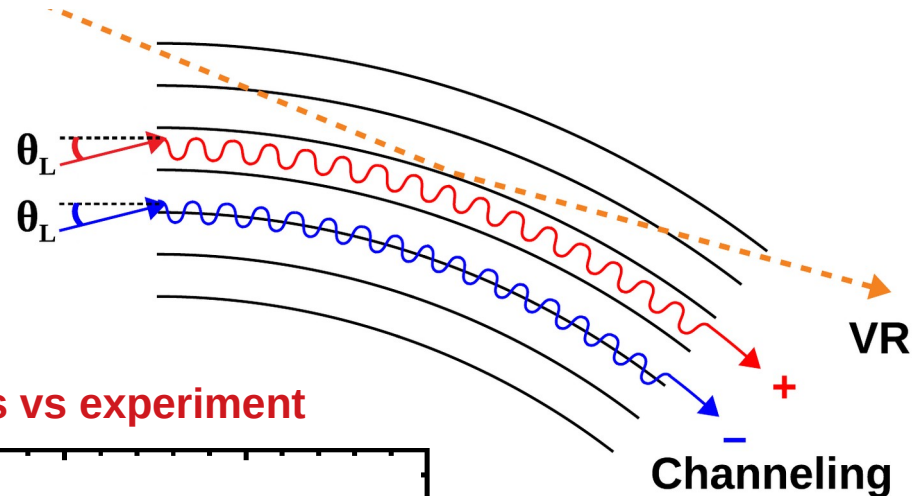
**G. Molière, Z. Naturforschg. 3A, 78-97 (1948);
H.A. Bethe Phys. Rev. 89, 6 (1953)

*Submitted to Eur. Phys. J. C

Geant4 channeling model validation: beam deflection by a bent crystal

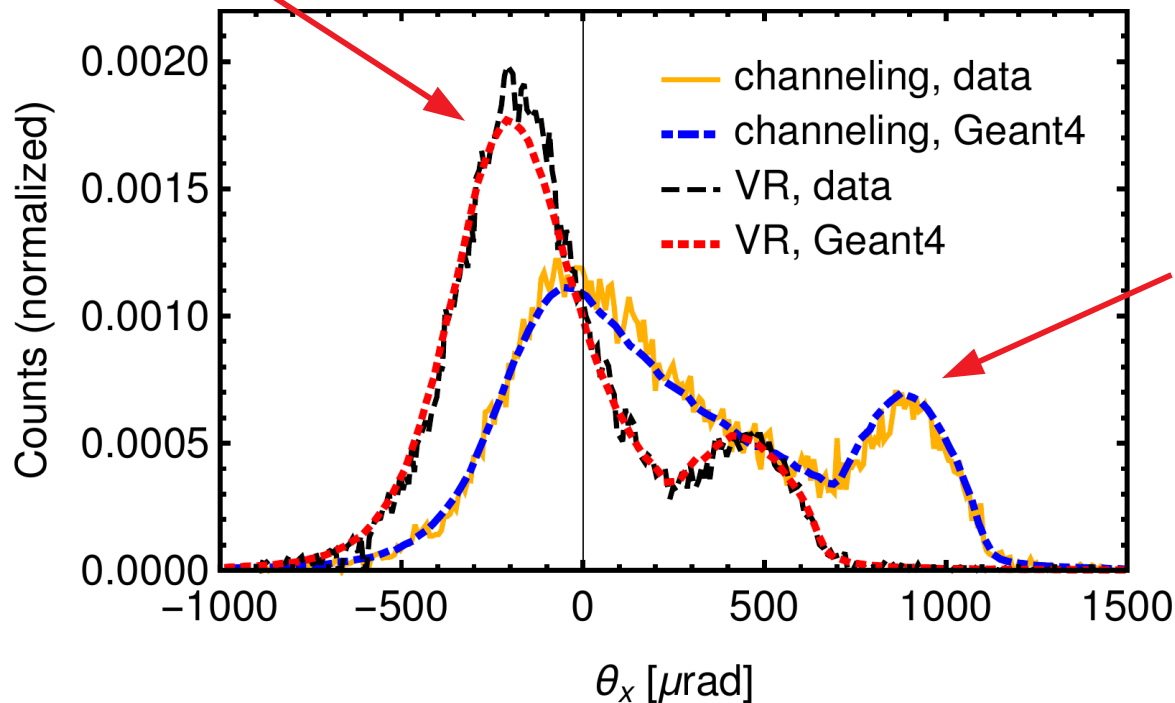
855 MeV
electrons

15 μm thick
bent crystal

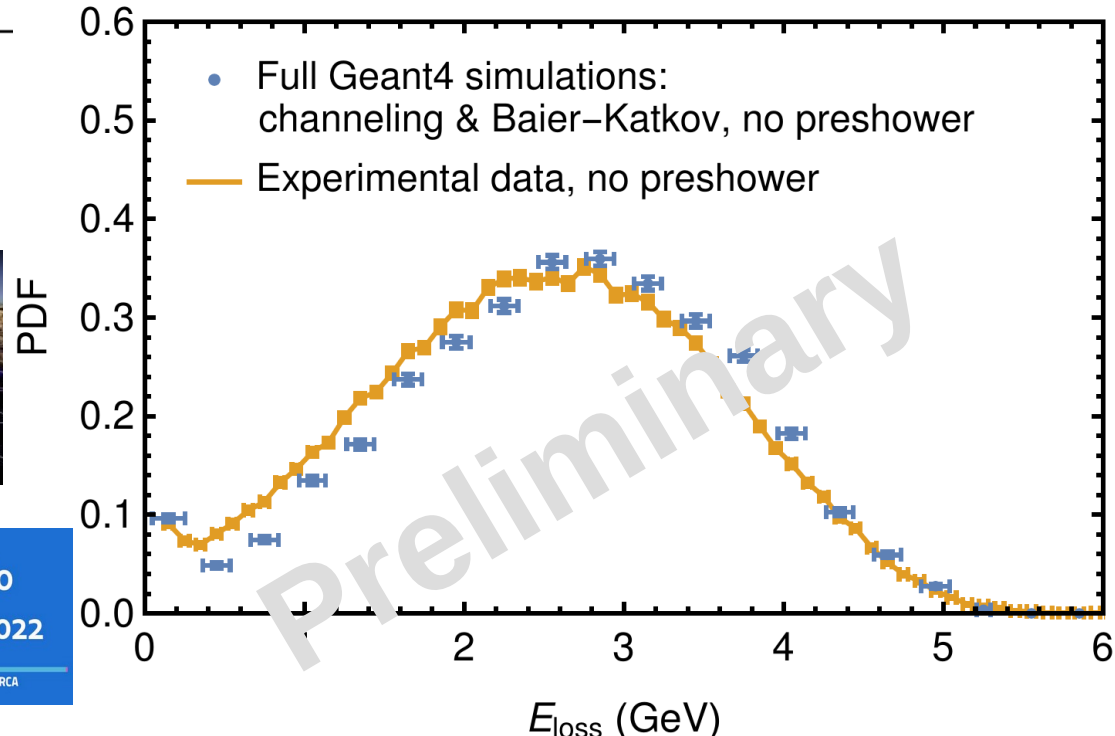
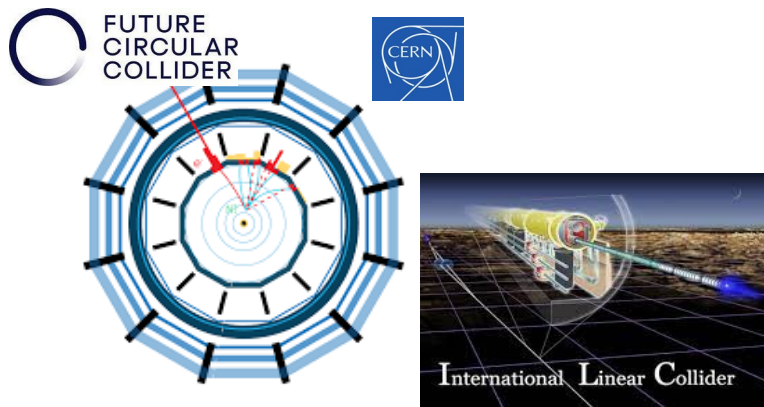
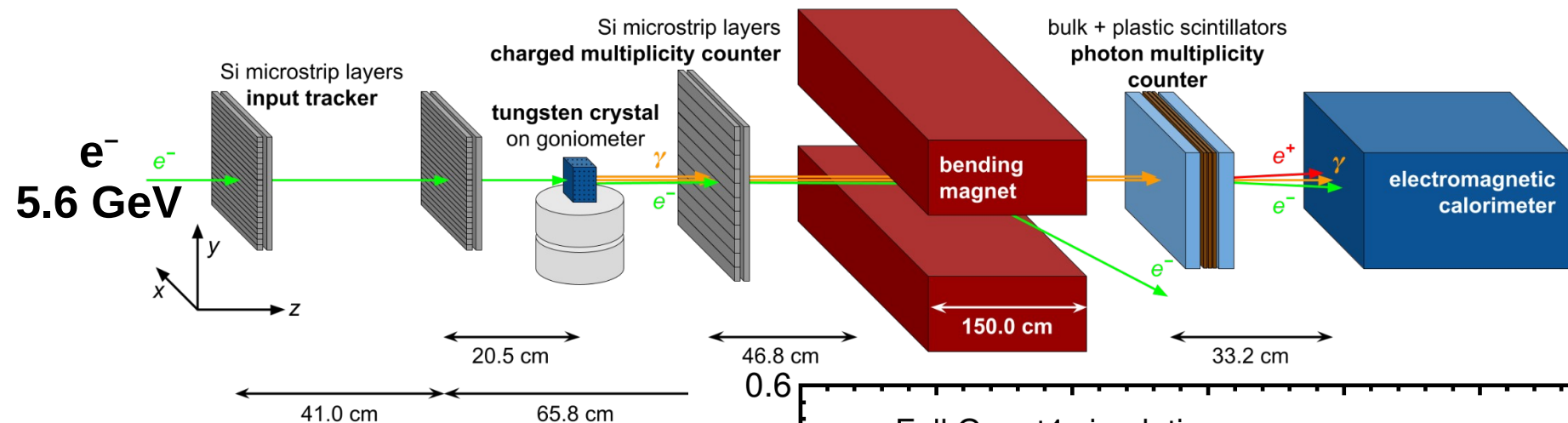


volume reflection (VR)

Geant4 simulations vs experiment



Full Geant4 simulations of the DESY experiment* for the FCC-ee positron source project

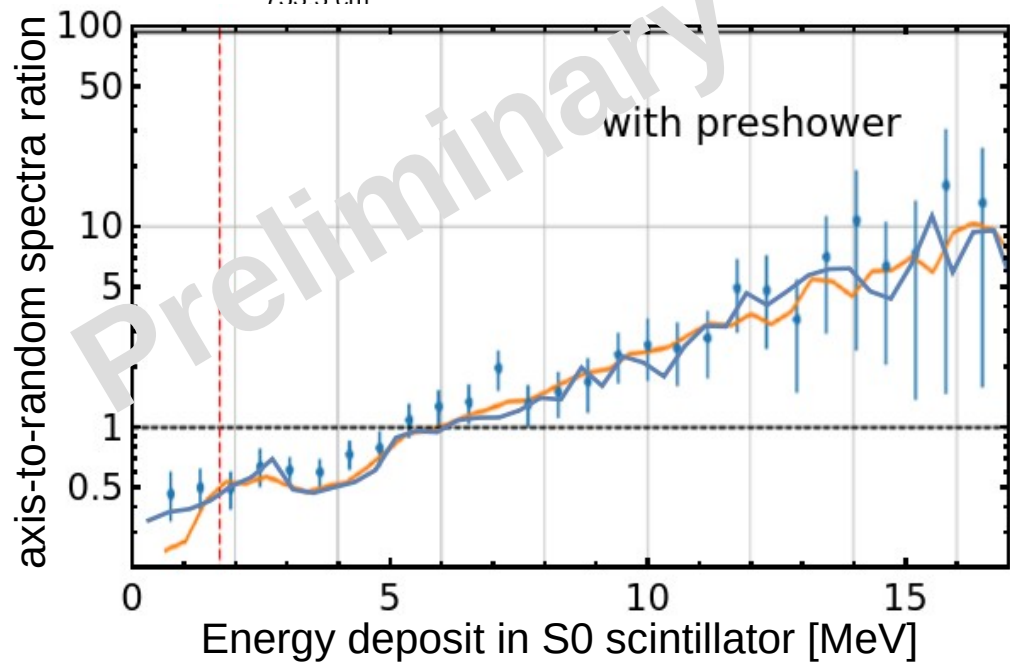
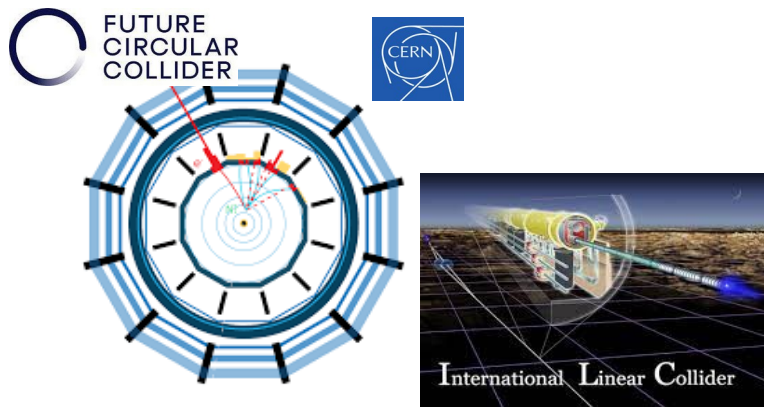
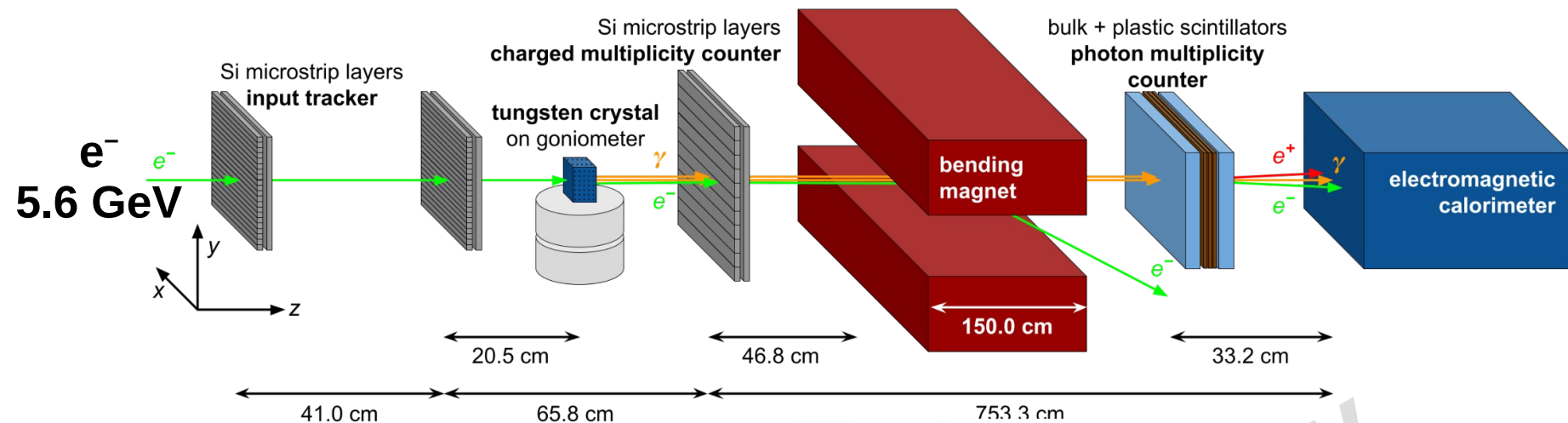


Intense positron source Based On Oriented crySTals - e+BOOST
 (PI L. Bandiera)
 PRIN2022-2022Y87K7X
 Financed by Italian Ministry of University and Research - PRIN project



*L. Bandiera et al. Eur. Phys. J. C 82, 699 (2022)

Full Geant4 simulations of the DESY experiment* for the FCC-ee positron source project



**Intense positron source Based On
Oriented crySTals - e+BOOST
(PI L. Bandiera)
PRIN2022-2022Y87K7X
Financed by Italian Ministry of
University and Research - PRIN project**



*L. Bandiera et al. Eur. Phys. J. C 82, 699 (2022)